



A Product Line of Diodes Incorporated

# LITE-ON SEMICONDUCTOR FUS1ME

#### SURFACE MOUNT **REVERSE VOLTAGE** - 1000 Volts FORWARD CURRENT - 1.0 Amperes FAST RECOVERY RECTIFIERS F1A FEATURES Fast switching for high efficiency F1A · For surface mounted applications · Glass passivated chip DIM. MIN. TYP MAX. Low reverse leakage current Α 3.50 3.80 3.90 · Low forward voltage drop в 1.70 1.90 2.00 · High current capability Qualified according to AEC-Q101 Rev\_C С 0.81 1.18 1.20 • Lead-Free Finish; RoHS Compliant (Notes 1 & 2) D 2.70 2.80 2.90 Halogen and Antimony Free. "Green" Device (Note 3) Е 0.80 1.00 1.35 F 0.05 0.15 0.30 **MECHANICAL DATA** G 0.35 0.85 0.60 Package: JEDEC DO-219AA н 0.03 0.07 0.10 · Package Material: "Green" molding compound, UL Flammability classification 94V-0,"Halogen-free". I. **0**° 5° 8° • Terminals: Lead Free Plating (Matte Tin Finish.) All dimension in millimeter. Component in accordance to RoHs 2002/95/EC Marking code: U1M • Weight: 16.5 mg (Approximate) MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

### ABSOLUTE RATING

PARAMETER		SYMBOL	VALUE	UNIT
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	1000	V
Maximum DC blocking voltage		V <sub>DC</sub>	1000	V
Average rectified forward current	@Tc=85°C	I <sub>(AV)</sub>	1.0	Α
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	30	А
Operating and Storage temperature range		$T_{J,} T_{STG}$	-55 ~ +150	°C

### STATIC ELECTRICAL CHARACTERISTICS

PARAMETER	TEST (	CONDITION	SYMBOL	TYP.	MAX	UNIT
Forward voltage	I <sub>F</sub> =1.0A	T <sub>J</sub> =25°C	V <sub>F</sub>	1.5	1.7	V
Leakage current	V <sub>R</sub> =1000V	Tյ=25°C Tյ=100°C	I <sub>R</sub>	0.2 10	5 100	uA
Typical junction capacitance (Note 4)			CJ	10		pF

### THERMAL PERFORMANCE

PARAMETER	SYMBOL	TYP.	UNIT	
	RthJ <sub>A</sub>	100		
Typical Thermal Resistance (Note 5)	RthJ∟	50	°C/W	
	RthJ <sub>c</sub>	55		

## DYNAMIC ELECTRICAL CHARACTERISTICS

PARAMETER	TEST CONDITION	SYMBOL	MAX		UNIT
Reverse recovery time	I <sub>F</sub> =0.5A ,I <sub>RR</sub> =0.25A,I <sub>R</sub> =1.0A	T <sub>RR</sub>	75		nS
Note:				REV3, Oct-2021, KS	SEP07

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm

antimony compounds.

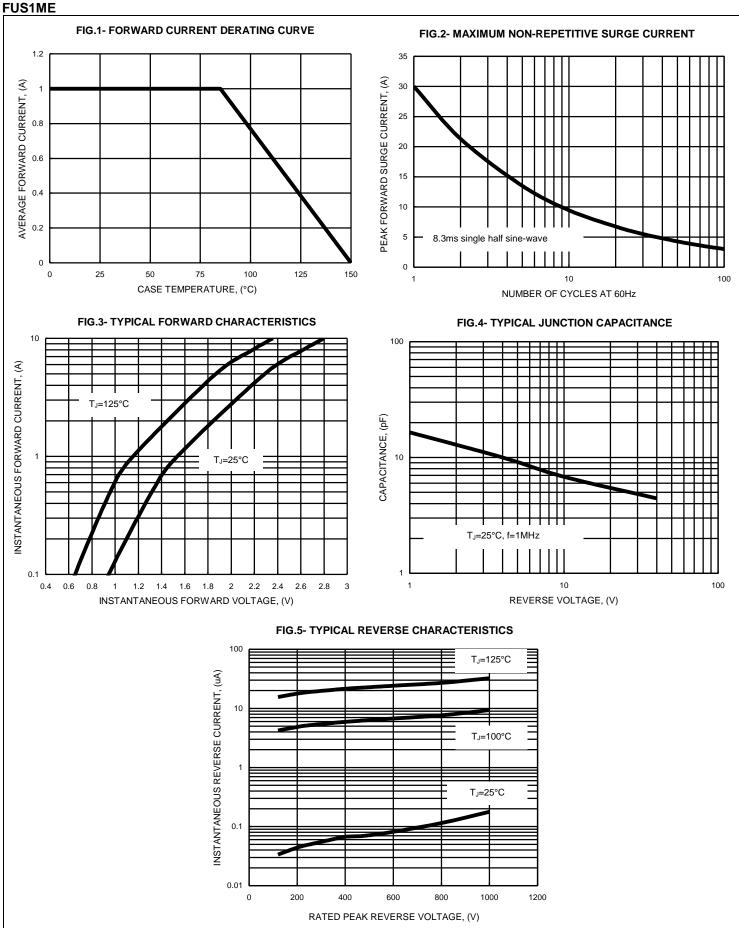
4. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

5. Thermal resistance test performed in accordance with JESD-51.

RATING AND CHARACTERISTIC CURVES

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# LITE-ON SEMICONDUCTOR

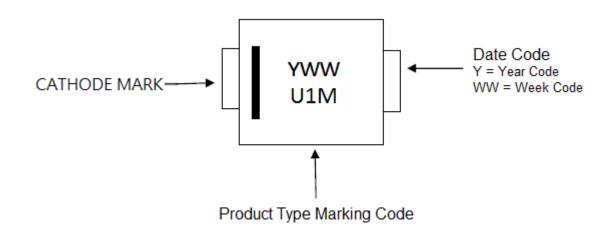




# **Ordering Information :**

Part Number	Packago	Packing		
	Package Qty.		Carrier	
FUS1ME-7	F1A	2500	Tape & Reel	
FUS1ME	F1A	10000	Tape & Reel	

# Marking Information :







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